

LOW SKEW 1 TO 4 CLOCK BUFFER

ICS621

Description

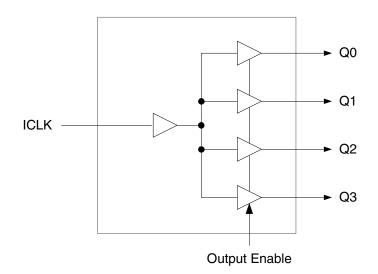
The ICS621 is a low skew, single input to four output, clock buffer. The device operates from a single 1.2 to 1.8 volt supply and has a 3.3 volt tolerant input, making it ideal for level translation.

IDT makes many non-PLL and PLL based low skew output devices as well as Zero Delay Buffers to synchronize clocks. Contact us for all of your clocking needs.

Features

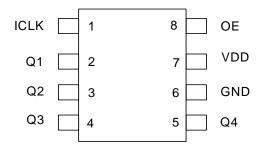
- Low skew outputs (150 ps)
- Packaged in 8-pin SOIC or 8-pin DFN (2x2mm)
- RoHS 5 or RoHS 6 (lead-free) package
- Low power CMOS technology
- Operating voltages of 1.2 V to 1.8 V
- Output Enable pin tri-states outputs
- 3.3 V tolerant input clock
- Industrial or commercial temperature ranges

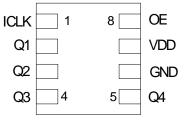
Block Diagram



Pin Assignment (8-pin SOIC)

Pin Assignment (8-pin DFN)





Pin Descriptions

Pin Number	Pin Name	Pin Type	Pin Description
1	ICLK	Input	Clock Input. 3.3 V tolerant input.
2	Q1	Output	Clock Output 1.
3	Q2	Output	Clock Output 2.
4	Q3	Output	Clock Output 3.
5	Q4	Output	Clock Output 4.
6	GND	Power	Connect to ground.
7	VDD	Power	Connect to +1.2 V or +1.8 V.
8	OE	Input	Output Enable. Tri-states outputs when low. Connect to VDD for normal operation.

External Components

A minimum number of external components are required for proper operation. A decoupling capacitor of 0.01 μ F should be connected between VDD on pin 7 and GND on pin 6, as close to the device as possible. A 33 Ω series terminating resistor may be used on each clock output if the trace is longer than 1 inch.

To achieve the low output skew that the ICS621 is capable of, careful attention must be paid to board layout. Essentially, all four outputs must have identical terminations, identical loads and identical trace geometries. If they do not, the output skew will be degraded. For example, using a 30Ω series termination on one output (with 33Ω on the others) will cause at least 15 ps of skew.

Absolute Maximum Ratings

Stresses above the ratings listed below can cause permanent damage to the ICS621. These ratings, which are standard values for IDT commercially rated parts, are stress ratings only. Functional operation of the device at these or any other conditions above those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods can affect product reliability. Electrical parameters are guaranteed only over the recommended operating temperature range.

Item	Rating
Supply Voltage, VDD	5 V
Output Enable and All Outputs	-0.5 V to VDD+0.5 V
ICLK	-0.5 V to 3.6 V (VDD > 0V)
Ambient Operating Temperature (industrial)	-40 to +85 ° C
Ambient Operating Temperature (commercial)	0 to +70 ° C
Storage Temperature	-65 to +150° C
Junction Temperature	125° C
Soldering Temperature	260° C

Recommended Operation Conditions

Parameter	Min.	Тур.	Max.	Units
Ambient Operating Temperature (industrial)	-40		+85	°C
Ambient Operating Temperature (commercial)	0		+70	°C
Power Supply Voltage (measured in respect to GND)	1.14		1.89	V

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DC Electrical Characteristics

VDD=1.2 V ±5%, Ambient temperature -40 to +85°C or 0 to +70°C, unless stated otherwise

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Units
Operating Voltage	VDD		1.14		1.26	V
Input High Voltage	V _{IH}	Note 1, ICLK, OE	0.65VDD		3.6	V
Input Low Voltage	V _{IL}	Note 1, ICLK, OE			0.35VDD	V
Output High Voltage	V _{OH}	I _{OH} = -2 mA	0.75VDD			V
Output Low Voltage	V _{OL}	I _{OL} = 2 mA			0.25VDD	V
Operating Supply Current	IDD	No load, 133 MHz		TBD		mA
Nominal Output Impedance	Z _O			20		Ω
Input Capacitance	C _{IN}	ICLK, OE pin		5		pF
Short Circuit Current	Ios			±20		mA

Notes: 1. Nominal switching threshold is VDD/2

VDD=1.5 V ±5%, Ambient temperature -40 to +85° C or 0 to +70° C, unless stated otherwise

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Units
Operating Voltage	VDD		1.425		1.575	V
Input High Voltage	V _{IH}	Note 1, ICLK, OE	0.65VDD		3.6	V
Input Low Voltage	V _{IL}	Note 1, ICLK, OE			0.35VDD	V
Output High Voltage	V _{OH}	I _{OH} = -6 mA	0.75VDD			V
Output Low Voltage	V _{OL}	I _{OL} = 6 mA			0.25VDD	V
Operating Supply Current	IDD	No load, 133 MHz		25		mA
Nominal Output Impedance	Z _O			20		Ω
Input Capacitance	C _{IN}	ICLK, OE pin		5		pF
Short Circuit Current	Ios			±28		mA

Notes: 1. Nominal switching threshold is VDD/2

VDD=1.8 V ±5%, Ambient temperature -40 to +85° C or 0 to +70° C, unless stated otherwise

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Units
Operating Voltage	VDD		1.71		1.89	V
Input High Voltage, ICLK	V _{IH}	Note 1, ICLK, OE	0.65VDD		3.6	V
Input Low Voltage, ICLK	V _{IL}	Note 1, ICLK, OE			0.35VDD	V
Output High Voltage	V _{OH}	I _{OH} = -8 mA	1.35			V
Output Low Voltage	V _{OL}	I _{OL} = 8 mA			0.45	V
Operating Supply Current	IDD	No load, 133 MHz		50		mA
Nominal Output Impedance	Z _O			20		Ω
Input Capacitance	C _{IN}	ICLK, OE pin		5		pF
Short Circuit Current	los			±50		mA

Notes: 1. Nominal switching threshold is VDD/2

AC Electrical Characteristics

VDD = 1.2 V ±5%, Ambient Temperature -40 to +85° C or 0 to +70° C, unless stated otherwise

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Units
Input Frequency			0		100	MHz
Output Rise Time	t _{OR}	20% to 80%, Note 3		1.0	1.5	ns
Output Fall Time	t _{OF}	80% to 20%, Note 3		1.0	1.5	ns
Propagation Delay	Note 1		2.2	3	5	ns
Output to Output Skew	Note 2	Rising edges at VDD/2		0	±150	ps

VDD = 1.5 V ±5%, Ambient Temperature -40 to +85° C or 0 to +70° C, unless stated otherwise

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Units
Input Frequency			0		166	MHz
Output Rise Time	t _{OR}	20% to 80%, Note 3		1.0	1.5	ns
Output Fall Time	t _{OF}	80% to 20%, Note 3		1.0	1.5	ns
Propagation Delay	Note 1		2.2	3	5	ns
Output to Output Skew	Note 2	Rising edges at VDD/2		0	±150	ps

VDD = 1.8 V \pm5%, Ambient Temperature -40 to +85° C or 0 to +70° C, unless stated otherwise

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Units
Input Frequency			0		200	MHz
Output Rise Time	t _{OR}	20% to 80%, Note 3		1.0	1.5	ns
Output Fall Time	t _{OF}	80% to 20%, Note 3		1.0	1.5	ns
Propagation Delay	Note 1		2.2	3	5	ns
Output to Output Skew	Note 2	Rising edges at VDD/2		0	±150	ps

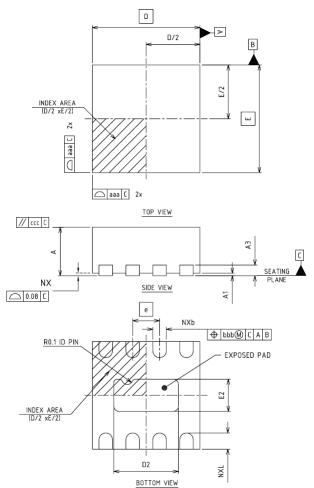
Notes: 1. With rail to rail input clock

- 2. Between any 2 outputs with equal loading.
- 3. Measured with a 15 pF load.

Thermal Characteristics

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Units
Thermal Resistance Junction to	θ_{JA}	Still air		150		° C/W
Ambient	θ_{JA}	1 m/s air flow		140		° C/W
	θ_{JA}	3 m/s air flow		120		° C/W
Thermal Resistance Junction to Case	$\theta_{\sf JC}$			40		° C/W
Case Temperature					120	°C
Thermal Resistance Junction to Top of Case	Ψ _{ЈТ}	Still air		20		° C/W

Package Outline and Package Dimensions (8-pin DFN 2x2mm, 0.5mm pitch) Package dimensions are kept current with JEDEC Publication No. 95,

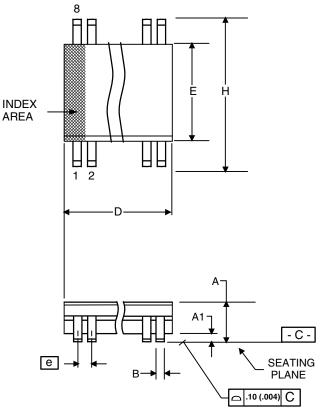


	Millimeters				
Symbol	Min	Max			
Α	0.80	1.00			
A1	0	0.05			
A3	0.20 Re	eference			
b	0.20	0.30			
N		8			
N _D		4			
N _E	0				
D	2.00 [BASIC			
Е	2.00 [BASIC			
е	0.50 I	BASIC			
D2	1.05	1.25			
E2	0.45	0.65			
L	0.20	0.40			
aaa	0.15				
bbb	0.10				
ccc	0.	10			

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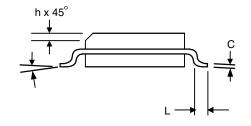
Package Outline and Package Dimensions (8-pin SOIC, 150 Mil. Narrow Body)

Package dimensions are kept current with JEDEC Publication No. 95



	Millimeters		Incl	nes*
Symbol	Min	Max	Min	Max
Α	1.35	1.75	.0532	.0688
A1	0.10	0.25	.0040	.0098
В	0.33	0.51	.013	.020
O	0.19	0.25	.0075	.0098
D	4.80	5.00	.1890	.1968
П	3.80	4.00	.1497	.1574
е	1.27 E	BASIC	0.050 BASIC	
I	5.80	6.20	.2284	.2440
h	0.25	0.50	.010	.020
L	0.40	1.27	.016	.050
α	0°	8°	0°	8°

^{*}For reference only. Controlling dimensions in mm.



Ordering Information

Part / Order Number	Marking	Shipping Packaging	Package	Temperature
621MILF	621MILF	Tubes	8-pin SOIC	-40 to +85° C
621MILFT	621MILF	Tape and Reel	8-pin SOIC	-40 to +85° C
621MLF	621MLF	Tubes	8-pin SOIC	0 to +70° C
621MLFT	621MLF	Tape and Reel	8-pin SOIC	0 to +70° C
621NLFT	1NL	Tape and Reel	8-pin DFN	0 to +70° C
621NILFT	1IL	Tape and Reel	8-pin DFN	-40 to +85° C

"LF" suffix to the part number are the Pb-Free configuration and are RoHS compliant.

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Revision History

Rev.	Originator	Date	Description of Change
Α	S. Sharma	06/08/06	New device/datasheet; Preliminary release.
В	S. Sharma	03/09/07	Removed Tape and Reel part number from DFN package ordering info.
С		05/27/08	Removed "Preliminary" and updated part ordering info.
D	R.Willner	08/01/08	Correct VIH values to reflect 3.3 V tolerant clock input
Е		10/27/09	Added EOL note for non-green parts
F		05/13/10	Removed EOL note and non-green parts
G	K.B.	05/13/10	Corrected DFN topmark.

FAN OUT BUFFER

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